LAMMPS implementation of rapid artificial neural network derived interatomic potentials

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Uses of atomistic potentials in metals

Over the past 30 years, atomistic simulations have been demonstrated to be a powerful tool for developing insight between the electronic scale and mesoscale.

They work well for characterizing:

- Grain boundary structures
- Twinning and martensitic transformations
- Dislocation reactions
- Segregation energies
- Etc.













Typical limitations of atomistic potentials

Disadvantages:

- Timescale is extremely limited cannot characterize diffusion processes
- Spatial scale is also very limited periodic and free surface simulations generally contain major deviations from experimental results because of scale
- Difficult to fit to multiple different kinds of properties
- Development of alloy potentials is very time consuming



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Types of atomistic potentials

Simple and efficient potentials:

- Lennard-Jones
- Embedded Atom Method

A little slower, but more accurate:

- MEAM
- MEAM-spline

Potentials designed for covalent bonding:

- ReaxFF
- Tersoff

Machine Learning:

- SNAP
- HDNNP (N2P2)
- QUIP (GAP)

Many other potential types also exist







Why do we want another one?

- Existing classical potentials have limited accuracy and are time-consuming to fit.
- Machine learning potentials can have much higher accuracy and the fitting can be streamlined.
- Therefore we have developed rapid artificial neural network (RANN) potentials

Why do we need another kind of Machine Learning potential?

- GAP is very slow
- SNAP is much faster, but has limited complexity due to the lack of hidden layers
- N2P2 was developed concurrently to our approach and is similar
 - RANN potentials are usually faster than N2P2
 - RANN is more user-friendly than N2P2
- No other existing ML method has screening







Screening

- Pair effects between a central atom and its neighbors are reduced or eliminated by other neighbors which are in between them.
- Our screening implementation is borrowed from the MEAM formulation.



 $cos\left(heta^{lphaeta\gamma}
ight)=rac{\mathbf{r}^{lphaeta}\cdot\mathbf{r}^{lpha\gamma}}{r^{lphaeta}r^{lpha\gamma}}$

 $X^{\gamma\beta} = \left(rac{r^{\gammaeta}}{r^{lphaeta}}
ight)^2$

$$X^{lpha\gamma} = \left(rac{r^{lpha\gamma}}{r^{lphaeta}}
ight)^2$$

$$C=rac{2\left(X^{lpha\gamma}+X^{\gammaeta}
ight)-\left(X^{lpha\gamma}-X^{\gammaeta}
ight)^2-1}{1-\left(X^{lpha\gamma}-X^{\gammaeta}
ight)^2}$$

$$f_c(x) = egin{bmatrix} 1 & x \geq 1 \ \left(1 - (1 - x)^4
ight)^2 & 0 < x < 1 \ 0 & x \leq 0 \end{cases}$$

$$S^{lphaeta\gamma} = f_c \left(rac{C-C_{min}}{C_{max}-C_{min}}
ight)$$

Baskes, Materials Chemistry and Physics, 50(2), 152-158, (1997).

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 $S^{lphaeta} = \prod_{\gamma} S^{lphaeta\gamma}$ Mississiddi state iniversity

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Structural Fingerprints

- Describe local environment in efficient, comprehensive and physically meaningful way
- Reduce dependence on exact number of neighbors
- Enforce ordering invariance and rotation invariance

$$A_n = \sum_{i} \left(\frac{r_i}{r_e}\right)^n \exp\left(-\alpha \frac{r_i}{r_e}\right) f(r_i)$$

$$A_{m,k} = \sum_{i,j} g_m \left(\cos \theta_{ij} \right) \exp \left(-\alpha_k \frac{r_i + r_j}{r_e} \right) f(r_i) f(r_j)$$

- We use two types of structural fingerprints, which primarily incorporate the effects of neighbor radial distribution and bond angle respectively
- Exponentially decaying intensity reflects underlying physics
- Physical motivation implies simpler network (fewer necessary inputs and neurons) and greater transferability
- These fingerprints are very similar to intermediate quantities computed by the MEAM potential







Machine Learning in LAMMPS

Machine learning works by having inputs fed through a series of "neurons" to produce a final output signal

"Non-deep" feedforward neural network hidden layer input layer output layer Atomic Structural Energies Fingerprints

hidden layer 1 hidden layer 2 hidden layer 3



Each neuron receives signals from neurons in the previous layer which are weighted and summed, then biases the result and feeds it through an activation function

$$Z_1 = \sum_i W_{n;i} A_{n;i} + B_n$$

 $A_{0:i} =$ Inputs (Structural fingerprints)

$$A_{n;i} = g_i(Z_{n;i})$$

$$\begin{aligned} A_{n,i} &= \\ g_i(\sum_j W_{n-1;i,j} A_{n-1;j} + B_{n-1;i}) \end{aligned}$$

Each layer may have a different number of neurons and the number of layers can be varied depending upon the problem requirements





The calibration process

The individual weights and biases of each neuron are the fitting parameters for the network

$$\frac{\partial Z_{n,i}}{\partial W_{n-2;j,k}} = \sum_{j} W_{n-1;i,j} \frac{\partial A_{n-1;j}}{\partial W_{n-2;j,k}}$$

$$A_{n;i} = g_i(Z_{n;i}) \qquad \qquad dA_{n;i} = dg_i(Z_{n;i})dZ_{n;i}$$

Because of the matrix-based structure of each neuron, the gradients with respect to all of the weights and biases are easily produced by backpropagation.

The large number of parameters indicates that overfitting is often a problem. Overfitting is avoided by checking the network performance on data which it was not trained with.





Derivation of Atomic Forces

The force on atom x in the η direction is defined as the derivative of the system energy with respect to the η coordinate of atom x's position

$$F_{x;\eta} = \frac{\partial E}{\partial x_{\eta}}$$

Using backpropagation, this may be derived analytical through the network

$$\frac{\partial Z_{n,i}}{\partial x_{\eta}} = \sum_{j} W_{n-1;i,j} \frac{\partial A_{n-1;j}}{\partial x_{\eta}} \qquad dA_{n;i} = dg_i (Z_{n;i}) dZ_{n;i}$$

Finally, the derivatives of the structural fingerprints must be obtained

$$dA_{0;n} = \sum_{i} \left(\frac{r_i}{r_e}\right)^n \exp\left(-\alpha \frac{r_i}{r_e}\right) f(r_i) \left(\frac{n}{r_i} - \frac{\alpha}{r_e} + \frac{df(r_i)}{f(r_i)}\right) dr_i$$
$$dA_{0;m,k} = \sum_{i,j} g_m \left(\cos^{\varsigma} \theta_{ij}\right) \exp\left(-\alpha_k \frac{r_i + r_j}{r_e}\right) f(r_i) f(r_j) \left(\frac{dg_m (\cos^{\varsigma} \theta_{ij})}{g_m (\cos^{\varsigma} \theta_{ij})} - \frac{\alpha}{r_e} + \frac{df(r_i)}{f(r_i)}\right) dr_i$$

$$dr_i = \frac{x_{\eta}}{r_i} dx_{\eta}$$







Making alloy potentials

 Each element has multiple sets of fingerprints depending on which neighbors are included

$$A_{n,X} = \sum_{i \in X} \left(\frac{r_i}{r_e}\right)^n \exp\left(-\alpha \frac{r_i}{r_e}\right) f(r_i)$$

$$A_{m,k,X,Y} = \sum_{i \in X, j \in Y} g_m \left(\cos^{\mathsf{g}} \theta_{ij} \right) \exp \left(-\alpha_k \frac{r_i + r_j}{r_e} \right) f(r_i) f(r_j)$$

- List of inputs expands from 32 to 104 for two different networks
- In general, complexity increases like $\sigma(N^2)$ (N = number of element types)







Choice of fingerprints and architecture

Effect of varying 3-body terms and hidden layer size on calculation error and speed for a Mg potential:

k_{tot}	m_{tot}	#SF	r_c	C_{min}	#NN	Training RMSE	Validation RMSE	Calculation speed
*3	4	13	6	0.49	20	0.90	2.25	21.77
3	4	13	8	0.49	20	0.67	1.64	15.74
3	4	13	10	0.49	20	0.69	1.71	10.71
2	4	13	12	0.25	38	0.89	1.71	5.56
2	4	13	12	0.49	20	1.09	1.05	8.26
2	4	13	12	0.70	18	0.93	1.08	9.34
3	4	17	12	0.25	38	0.80	1.03	5.07
3	4	17	12	0.49	20	0.71	1.38	8.04
3	4	17	12	0.70	18	0.80	1.06	8.75
5	3	20	12	0.25	38	1.57	2.95	4.91
5	3	20	12	0.49	20	2.80	3.08	7.88
5	3	20	12	0.70	18	2.88	3.10	8.32
MEAM [33]								61.963
N2P2 [27]								5.12

Effect of screening on a single fingerprint as the lattice parameter is scaled:



The effect of screening on computation speed can be positive or negative, but generally speeds up potentials with normal cutoff radii.







<u>Functional Form of the Neural</u> Network Potential for Ti

n = 1 through 4, m = 0 through 6, k = 1 through 4

$$A_{0;n} = \sum_{i} \left(\frac{r_i}{r_e}\right)^n \exp\left(-\alpha \frac{r_i}{r_e}\right) f(r_i) \qquad \begin{array}{l} r_e = \\ r_c = \\ dr = \\ dr = \\ \alpha = \\ r_e = \\ dr = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i + r_j \\ r_i \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i + r_j \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i + r_j \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i + r_j \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_i) f(r_j) \qquad \begin{array}{l} r_e = \\ \alpha_k = \begin{bmatrix} r_i \\ \alpha_k \end{bmatrix} f(r_i) f(r_i) f(r_i) f(r_i) f(r_i) f(r_i) f(r_i) \ \end{array} f(r_i) f$$

Architecture: Input layer: 32 neurons Hidden Layer 1: 20 neurons Output Layer: 1 neuron

$$A_{n,i} = g_i(\sum_j W_{n-1;i,j}A_{n-1;j} + B_{n-1;i})$$

The total size of the input layer is 32 = $n_{ma}x + (m_{ma}x + 1)k_{ma}x$

$$r_e = 2.91^5$$

 $r_c = 6.75$
 $dr = 0.5$
 $\alpha = 4.65$
 $\alpha_k = [1\ 2\ 4\ 8]$

Activation Functions: $g_i(x) = 0.1x + 0.9 \ln(e^x + 1)$ $g_2(x) = x$

681 individual weights and biases are fit





How to use RANN in LAMMPS

atomtypes: Input script: Mg mass:Mg: 24.305 Syntax like eam/alloy and many other pairs: fingerprints:Mg Mg: radialpower 0 pair_style rann fingerprints:Mg_Mg_Mg: bondpower 0 pair_coeff * * potential_file.nn Element1 ... fingerprintconstants:Mg_Mg:radialpower_0:re: 3.1936 fingerprintconstants:Mg_Mg:radialpower_0:rc: Potential file syntax: fingerprintconstants:Mg_Mg:radialpower_0:dr: 2.8064 The potential file is designed to be human fingerprintconstants:Mg_Mg:radialpower_0:n: readable. It is divided into sections by fingerprintconstants:Mg Mg:radialpower 0:o: -1 fingerprintconstants:Mg_Mg:radialpower_0:alpha: keywords: 5.52 5.52 5.52 5.52 5.52 fingerprintconstants:Mg_Mg_Mg:bondpower_0:re: atomtypes 3.1936 fingerprintconstants:Mg Mg Mg:bondpower 0:rc: mass fingerprintconstants:Mg_Mg_Mg:bondpower_0:dr: 2.8064 fingerprintsperelement fingerprintconstants:Mg Mg Mg:bondpower 0:m: fingerprints fingerprintconstants:Mg_Mg_Mg:bondpower_0:alphak: 1 2 6 9 fingerprintconstants:Mg Mg Mg:bondpower 0:k: fingerprintconstants networklayers:Mg: screening (optional) layersize:Mg:0: networklayers 37 layersize:Mg:1: 20 layersize layersize:Mg:2: 1 weight weight:Mg:0: -2.854926896534886 1.551245978744016 -5.2994867159052261.30303239306658 bias -3.927350992087088 0.806210218127504 -1.428595777065406-0.168066964538803-0.728351260519369-0.1574506400682105.491434639296052 1.080334461269439 -2.130535923458539 -1.156477049555650-2.051010848588853-0.782611130585220 activationfunctions -2.387644217672982 -5.576794096713175 -4.606523573915344 -3.318269168403370-6.29253905809722918.703592187192875 -2.3815903802449502.799241528343801 calibrationparameters (ignored) -2.407391034332221 4.405517388343755 -9.491423045727968 8.229571895198635 0.170484581466223 2.527344035625121 -0.067244382960372 1.282379910053745 0.065724915799647 1.113377435138116 -0.5735350029471381.560506886857219 MISSISSIPPI STATE UNIVERSITY.



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Case Example: Single Element Zn



Case Example: Single Element Zn

- Two new MEAM potentials for Zn were published in 2018 independently by two different groups
- Zn is a critical alloying element in many Iron, Aluminum and Magnesium materials
- Because of its very high c/a ratio, Zn is very difficult to accurately simulate
- BJ Lee et al's potential captures the energy difference from fcc to hcp well, but has very bad lattice parameters and elastic constants
- Dickel et al's potential captures the lattice parameters and elastic constants well, but incorrectly predicts fcc as more stable than hcp







New RANN potential for zinc



Nitol, Dickel, and Barrett. Comp. Mat. Sci. 188 (2021): 110207.



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Applications for Ti and Zr



New potentials for Ti and Zr correctly capture not only melting but also phase transitions between three solid phases as a function of temperature and pressure!







Applications for Mg



- 2nd order pyramidal <c+a> slip in Mg is an important plastic mechanism
- Recent understanding has been that the edge dislocation of this mode spontaneously dissociate, becoming sessile.
- Our new potential shows the dislocations can still migrate at low stress even after dissociating.
- A recent N2P2 potential by Stricker et al. confirms the same results
- Other MEAM and EAM potentials for Mg cannot produce this mechanism.





